

isc N-Channel MOSFET Transistor

IPD60R450E6,IIPD60R450E6

FEATURES

- Static drain-source on-resistance:
 R_{DS}(on)≤0.45Ω
- Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

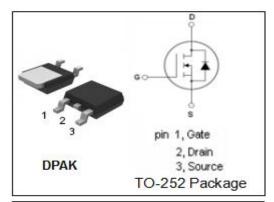
· Fast switching

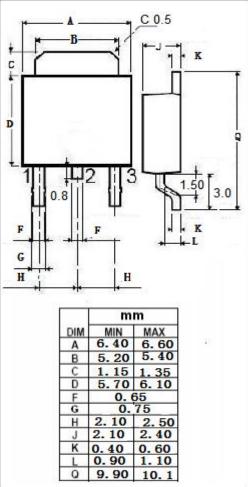
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	600	V	
V_{GS}	Gate-Source Voltage	±20	V	
ID	Drain Current-Continuous	9.2	А	
I _{DM}	Drain Current-Single Pulsed 26		А	
P _D	Total Dissipation @T _C =25°C	74	W	
Tj	Max. Operating Junction Temperature 150		$^{\circ}$ C	
T _{stg}	Storage Temperature	-55~150	$^{\circ}$	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(j-c)	Channel-to-case thermal resistance	1.7	°C/W
Rth(j-a)	Channel-to-ambient thermal resistance	62	°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =0.25mA	600			V
$V_{\text{GS(th)}}$	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.28mA	2.5		3.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =3.4A			0.45	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} =20V; V _{DS} =0V			0.1	μ A
I _{DSS}	Drain-Source Leakage Current	V _{DS} =600V; V _{GS} = 0V			1	μА
V _{SD}	Diode forward voltage	I _F =4.2A, V _{GS} = 0V		0.9		V

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